

# SANYO Semiconductors DATA SHEET

# MCH6603 — General-Purpose Switching Device Applications

### **Features**

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 1.5V drive.
- · Composite type with 2 MOSFETs contained in a single package, facilitating high-density mounting.

# **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		-50	V
Gate-to-Source Voltage	VGSS		±10	V
Drain Current (DC)	ID		-0.14	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-0.56	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm <sup>2</sup> X0.8mm) 1unit	0.8	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			1.1
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-50			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =-50V, V <sub>GS</sub> =0V			-1	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±8V, V <sub>DS</sub> =0V			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =-10V, I <sub>D</sub> =-100μA	-0.4		-1.4	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =-10V, I <sub>D</sub> =-40mA	70	110		mS
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	I <sub>D</sub> =-40mA, V <sub>G</sub> S=-4V		18	23	Ω
	RDS(on)2	ID=-20mA, VGS=-2.5V		20	28	Ω
	R <sub>DS</sub> (on)3	ID=-5mA, VGS=-1.5V		30	60	Ω
Input Capacitance	Ciss	V <sub>DS</sub> =-10V, f=1MHz		7.4		pF
Output Capacitance	Coss	V <sub>DS</sub> =-10V, f=1MHz		4.2		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =-10V, f=1MHz		1.3		pF

Marking: FC Continued on next page.

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# **SANYO Semiconductor Co., Ltd.**

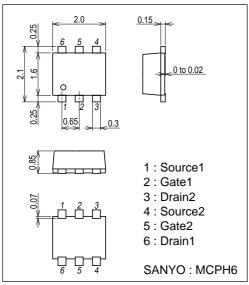
# MCH6603

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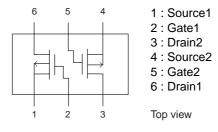
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		20		ns
Rise Time	t <sub>r</sub>	See specified Test Circuit.		35		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.		160		ns
Fall Time	tf	See specified Test Circuit.		150		ns
Total Gate Charge	Qg	V <sub>DS</sub> =-10V, V <sub>GS</sub> =-10V, I <sub>D</sub> =-70mA		1.40		nC
Gate-to-Source Charge	Qgs	VDS=-10V, VGS=-10V, ID=-70mA		0.16		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =-10V, V <sub>GS</sub> =-10V, I <sub>D</sub> =-70mA		0.23		nC
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-70mA, V <sub>GS</sub> =0V		-0.85	-1.2	V

### **Package Dimensions**

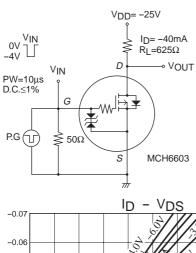
unit : mm 7022A-006

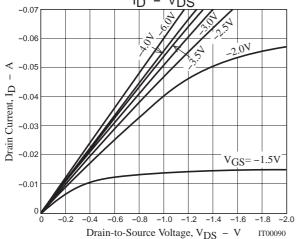


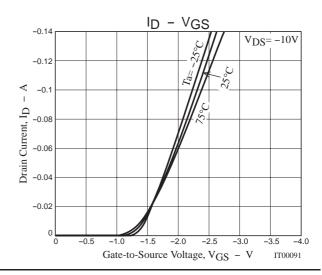
#### **Electrical Connection**



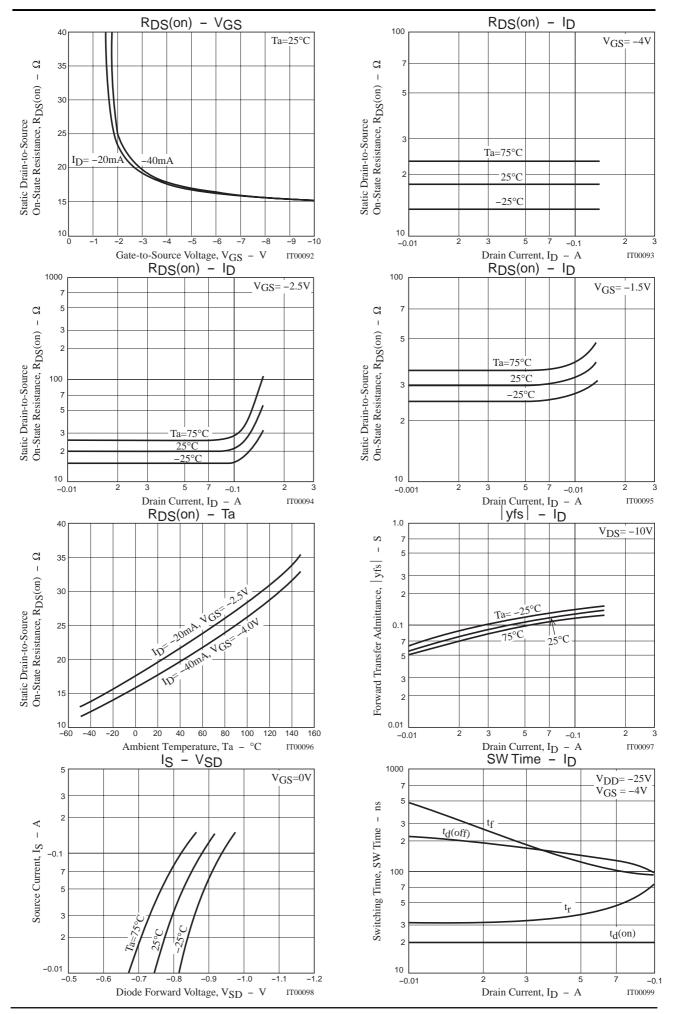
# **Switching Time Test Circuit**



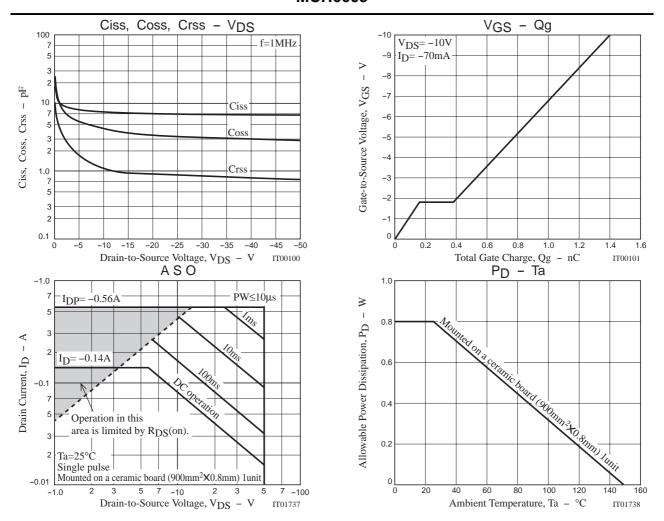




# MCH6603



#### MCH6603



Note on usage: Since the MCH6603 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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